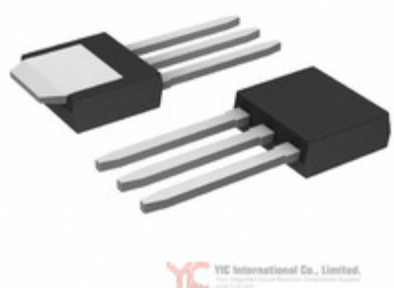




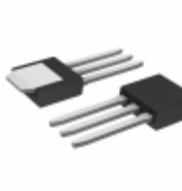
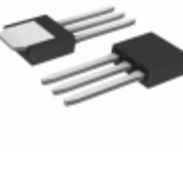



	<h2 style="color: red;">GP2M004A060PG</h2>	
	Hersteller-Teilenummer:	GP2M004A060PG
	Hersteller / Marke:	Global Power Technologies Group
	Teil der Beschreibung:	MOSFET N-CH 600V 4A IPAK
Datenblätter:	 GP2M004A060PG.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 3500 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	GP2M004A060PG
Hersteller	Global Power Technologies Group
Beschreibung	MOSFET N-CH 600V 4A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3500 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	86.2W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A (Tc)
Rds On (Max) @ Id, Vgs	2.5 Ohm @ 2A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	12nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	545pF @ 25V
Verpackung	Tube

GP2M004A060PG ist neu im Original, Suche GP2M004A060PG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie GP2M004A060PG Global Power Technologies Group mit Garantie und Vertrauen. Anfrage GP2M004A060PG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>GP2M005A050CG Global Power Technologies Group MOSFET N-CH 500V 4.5A DPAK</p>	 <p>GP2M004A060CG Global Power Technologies Group MOSFET N-CH 600V 4A DPAK</p>	 <p>GP2M004A060FG Global Power Technologies Group MOSFET N-CH 600V 4A TO220F</p>	 <p>GP2M002A065PG Global Power Technologies Group MOSFET N-CH 650V 1.8A IPAK</p>
 <p>GP2M004A065PG Global Power Technologies Group MOSFET N-CH 650V 4A IPAK</p>	 <p>GP2M002A065HG Global Power Technologies Group MOSFET N-CH 650V 1.8A TO220</p>	 <p>GP2M004A065CG Global Power Technologies Group MOSFET N-CH 650V 4A DPAK</p>	 <p>GP2M004A065HG Global Power Technologies Group MOSFET N-CH 650V 4A TO220</p>

heiße Teile

Mehr

GP200E1M-G1	GP200E1MTR-G1	GP200EMTR-G1	GP200MTR-G1	GP2A231LRSA
GP2A25J0000F	GP2A25J0000F	GP2A25NJ	GP2A28A1J00F	GP2A28N1J00F
GP2AP002A00F	GP2AP002S00F	GP2AP003A10F	GP2AP007A00F	GP2AP008T00F
GP2AP030A00F	GP2AP052A00F	GP2AP052A00F	GP2L26K2	GP2M002A060FG
GP2M004A065FG	GP2M004A065PG	GP2M005A050PG	GP2M005A060CG	GP2M005A060FG
GP2M005A060PGH	GP2M008A060FGH	GP2M010A060F	GP2M010A065F	GP2M011A090NG
GP2M012A080NG	GP2M020A050H	GP2M020A060N	GP2S24J0000F	GP2S27T3
GP2S27T3J00F	GP2S27V6	GP2S29SVJ00F	GP2S40JJ000F	GP2S700HCP
GP2S700HCP	GP2W0004YP	GP2W0110YPS	GP2W0112YPOF	GP2W0118YPS
GP2W0150YP0F	GP2W3104XP0F	GP2W3104YP0F	GP2W3106YP0F	GP2W3152YP0F

Contact us: Info@Y-IC.com

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